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A combination of experimental and numerical method for optimizing the sensitivity of ultra-thin piezoelectric sensor with interdigitated electrodes

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Supplementary material for this article is available online

Abstract

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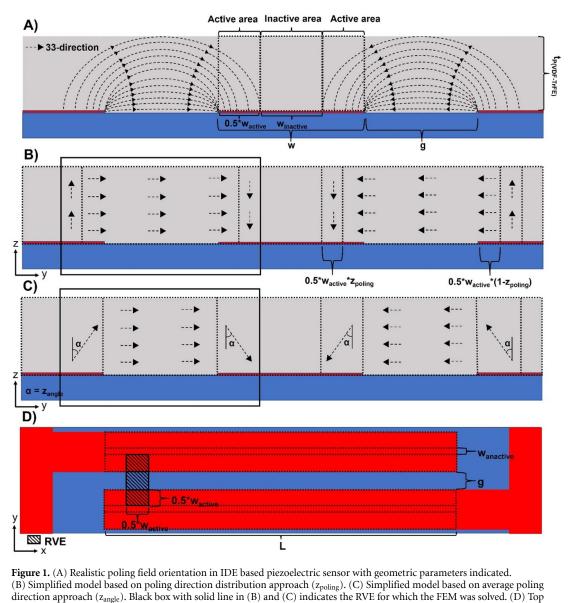
We report the development of a finite element model (FE-model) for ultra-thin piezoelectric poly(vinylidene-trifluoroethylene) sensor with interdigitated electrodes (IDE) which includes the effect of a non-homogenous poling field determined via the combination of experimental and numerical methods. The non-homogenous poling magnitude is estimated by comparing the remanent polarization (P_r) of IDE based device to the P_r of the same material in metal–insulator–metal electrode configuration. The non-homogenous poling orientation is estimated by comparing the experimentally determined normal mode sensitivity (S_n) values to FE-modelled sensitivity values with different poling orientation distributions. The poling orientation distribution is modelled using two approaches: (a) 33-direction parallel and perpendicular to the electrode plane and (b) 33-direction defined by an average angle. The first approach yields the best correspondence with the experimental results ($R^2 = 94.70\%$ and $\sigma = 0.10 \text{ pC N}^{-1}$) and it is used to optimize the device geometry and poling condition for maximum S_n .

1. Introduction

polymeric materials Piezoelectric based on poly(vinylidenefluoride-trifluoroethylene) P(VDF-TrFE) have been recently employed in the fabrication of ultra-thin sensors which enable user-friendly and comfortable measurement of mechanically induced bio-signals [1-4]. However, traditional piezoelectric sensors with metal-insulator-metal (MIM) electrode configuration have limitations in this regard because decreasing their thickness increases their capacitance and thereby results in lower voltage sensitivity of the device. Novel electrode configurations based on interdigitated electrode (IDE) structure have been proposed to combat this issue; in this case, the device capacitance does not depend on the thickness of the piezoelectric layer to the same extent (see e.g. [5]

and table S1), and therefore the device voltage sensitivity is less affected by the decreasing piezoelectric layer thickness. This enables the fabrication of very thin, yet high sensitivity devices as demonstrated by Lozano *et al* [1].

However, in addition to the capacitance, the device sensitivity also depends on the charge generation ability of the piezoelectric material, which for MIM based devices is well understood, but for IDE based devices less so: the main challenge in understanding the IDE based device charge generation is related to the non-uniform poling field between the consecutive electrodes. As the direction of the electric field lines determines the poling direction of the material, for example the positive 33-direction in IDE based device may point parallel or perpendicular to the electrode plane, or any angle between



direction approach (z_{angle}). Black box with solid line view of pair of IDEs with RVE marked.

them, depending on the point under investigation (i.e. various 33-directions will encompass all of 360°; see figure 1(A); compare this to a MIM based device where the 33-direction always points to one direction i.e. perpendicular to the electrode plane. Furthermore, the magnitude of the poling varies significantly in the case of IDE, whereas for MIM it is homogenous throughout the material: electrostatic FE-modelling [6-10] has shown that the IDE-based devices have an inactive area close to the centerline of the electrode where the electric field magnitude, and therefore also the poling magnitude, is zero. Thus, to fully understand the factors affecting the sensitivity of the IDE based device, one would have to solve for the net effect generated by the various magnitudes and directions of poling throughout the material. Beckert and Kreher [6] used a two-step approach to achieve this: they first modelled the non-uniform electric

field and then used these results to assign a local poling direction/magnitude for each element of the piezoelectric model. However, this may be challenging because of the time and computational power required in dividing the piezoelectric material model into small elements, assigning each of these with a local poling direction/magnitude and finally solving the complex model. Toprak and Tigli [9] used similar two step approach; however, they simplified the latter step by using an average poling orientation/magnitude on top of the electrode instead of element specific local orientation/magnitude.

In this article we try to improve upon the latter methods by basing the determination of nonhomogenous poling orientation/magnitude on experimental results instead of electrostatic FEmodelling. The non-homogenous poling magnitude is estimated based on remanent polarization (P_r) measurement. Specifically, we assume that the poling magnitude in the active area is 100%, and in the inactive area 0%. The width of the active and inactive area is then estimated by comparing the measured $P_{\rm r}$ value for the IDE to the $P_{\rm r}$ of the same material in the MIM configuration. The non-homogenous poling orientation is estimated by comparing the experimentally determined sensitivity values to FEmodelled sensitivity values with different poling orientation distributions. Specifically, the poling orientation distribution is included in the FE-model using two approaches: (a) the active area is divided into poling orientations which are parallel and perpendicular to the electrode plane (see figure 1(B)) and (b) the poling orientation in the active area is described by average angle as suggested by Toprak and Tigli [9] (see figure 1(C)). A statistical analysis is then performed to predict the poling orientation distribution based on the sample dimensions and the poling condition, and the resulting regression equation is used as an input in the FE-model. We show that the approach (a) yields the best match between the FEmodelled and experimentally determined sensitivity values. Finally, we use the thus generated FE-model to optimize the sample dimensions and the poling condition for maximum sensitivity.

2. Results and discussion

2.1. Sample description

IDE based piezoelectric samples with inkjet printed PEDOT:PSS interdigitated electrodes and bar coated P(VDF-TrFE) layer were fabricated on top of a Parylene-C polymer as described in our previous publication [1]. Seventeen IDE samples were included in the analysis with P(VDF-TrFE) thickness ($t_{P(VDF-TrFE)}$) ranging from 5.7 μ m to 25.2 μ m and electrode width (w) ranging from 134 μ m to 156 μ m; the electrode-to-electrode gap (g) is dependent on electrode pitch (200 μ m) and ranges from 44 μ m to 66 μ m (see figure 1). The normal mode sensitivity (S_n) and remanent polarization (P_r) of each IDE sample was measured as described in experimental section. The results are summarized in table S1.

2.2. Non-homogenous poling magnitude

Remanent polarization (P_r) values extracted from the polarization-electric field loop (PE-loop) measurements were employed in determining the width of the inactive area at the center of the finger electrodes. The remanent polarization of the IDE samples ($P_{r.IDE}$) is extracted from PE-loop measurement where the polarization (P) is determined as (see figure 2):

$$P = Q \cdot A^{-1} = Q \cdot \left(\frac{(N-1) \cdot (L \cdot w)}{2}\right)^{-1}, \quad (1)$$

where Q is the measured charge, A the IDE electrode area from which the charge is measured, N

the number of electrodes, *L* the overlapping length of the electrodes and *w* the width of the electrodes [1, 11, 12]. However, this does not take into account the inactive area in the middle of the finger electrodes. A more realistic approach would be to assume that the P(VDF-TrFE) reaches its maximum poling magnitude ($P_r = 7.3 \ \mu C \ cm^{-2}$ as measured using the MIM reference device, see figure 2) in the active area while the poling magnitude is assumed to be 0 $\mu C \ cm^{-2}$ in the inactive area. In this case the equation (1) can be written as

$$P_{\text{active}} = Q \cdot A_{\text{active}}^{-1} = Q \cdot \left(\frac{(N-1) \cdot (L \cdot w_{\text{active}})}{2}\right)^{-1},$$
(2)

where P_{active} is the polarization measured from the active area, A_{active} the active area and w_{active} the width of the active area. Because the measured charge must be the same in both cases, we end up with the following equation:

$$P_{\text{active}} \cdot A_{\text{active}} = P \cdot A \xrightarrow{\text{yields}} A_{\text{active}} = \frac{P}{P_{\text{active}}} \cdot A. \quad (3)$$

As per our assumption, we may now replace the P_{active} with MIM remanent polarization $(P_{r,\text{MIM}} = 7.3 \ \mu\text{C cm}^{-2}$, see figure 2) while the *P* is the $P_{r,\text{IDE}}$ extracted from the original PE-loop measurement:

$$\begin{aligned} A_{\text{active}} &= \frac{P_{\text{r.IDE}}}{P_{\text{r.MIM}}} \cdot A \\ &= P_{\text{r.ratio}} \cdot A \stackrel{\text{yields}}{\to} \frac{(N-1) \cdot (L \cdot w_{\text{active}})}{2} \\ &= \frac{(N-1) \cdot (L \cdot P_{\text{r.ratio}} \cdot w)}{2} \stackrel{\text{yields}}{\to} w_{\text{active}} \\ &= P_{\text{r.ratio}} \cdot w. \end{aligned}$$
(4)

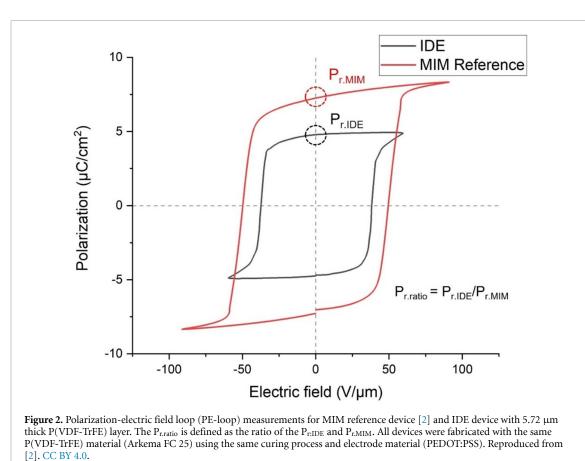
The width of the inactive area (w_{inactive}) is then simply:

$$w_{\text{inactive}} = (1 - P_{\text{r.ratio}}) \cdot w. \tag{5}$$

The results are summarized in table S1.

2.3. Non-homogenous poling orientation

A 3D FE-model for the IDE based piezoelectric device in the S_n measurement situation was generated using COMSOL software with piezoelectric multiphysics module. The geometry was miniaturized such that it consisted of the representative volume element (RVE) of the IDE (see figures 1(B)–(D)). The inactive area was omitted from the model as it is assumed to have 0% poling magnitude and it does not therefore contribute toward piezoelectric charge generation. In contrast, the poling magnitude in the active area is assumed to be complete (100%) and the piezoelectric properties are therefore described by the full coupling matrix of P(VDF-TrFE) [13]. These and other relevant material parameters are given in SI.



The effect of non-homogenous poling orientation was included in the model using two approaches:

- Model 1) The active area on top of the electrode is divided to areas where the 33-direction is perpendicular (in negative/positive *z*-direction, see figure 1(B)) and parallel to the electrode plane (in the positive *y*-direction). A unitless parameter z_{poling} , with values between 0 and 1, was used to describe the poling direction distribution; for example, $z_{\text{poling}} = 0.4$ indicates that 40% of the active area on top the electrode is poled in direction perpendicular to electrode plane and 60% in direction parallel to electrode plane.
- Model 2) The poling direction is uniform over the active area of the electrode, but the 33-direction is at an angle when compared to the *z*-axis (see figure 1(C)). This corresponds to the average poling direction approach suggested by Toprak and Tigli [9]. z_{angle} is used to describe the angle between the 33-direction and *z*-axis and it can take values between 0 and 90°.

Finally, a compressive force was applied in negative z-direction with pressure equal to the experimental situation while evaluating the surface charge generated on one of the electrodes. This was translated to total charge output (Q_{out}) by multiplying it with the number of RVEs activated in the S_n measurement:

$$Q_{out} = N_{RVE} \cdot Q_S = N_{RVE} \oiint D_n \cdot dS \tag{6}$$

where N_{RVE} is the number of RVEs, Q_{s} the surface charge, D_{n} the normal component of the electric displacement field and *S* the surface where the D_{n} is evaluated (i.e. the electrode surface). Considering the RVE geometry where the width and depth of the electrode is equal to $0.5 \cdot w_{\text{active}}$, we can write:

$$Q_{\text{out}} = N_{\text{RVE}} \int_{0}^{0.5 \cdot w_{\text{active}}} \int_{0}^{0.5 \cdot w_{\text{active}}} D_{\text{n}} \cdot dxdy$$
$$= N_{\text{RVE}} \cdot 0.25 \cdot w_{\text{active}}^2 \cdot D_{\text{n}}.$$
(7)

However, the N_{RVE} decreases as the w_{active} increases. Consider a sample where the piezoelectric material on top of *N* electrode pairs with overlapping length *L* is compressed uniformly. Then:

$$N_{\rm RVE} = N \cdot 2 \cdot \frac{L}{0.5 \cdot w_{\rm active}}.$$
 (8)

Combining equations (4)–(8) yields:

$$Q_{\text{out}} = N \cdot L \cdot w_{\text{active}} \cdot D_n = N \cdot L \cdot P_{\text{r.ratio}} \cdot w \cdot D_n.$$
(9)

The S_n can be then solved using the formula:

$$S_{\rm n} = \frac{Q_{\rm out}}{F} = \frac{N \cdot L \cdot P_{\rm r.ratio} \cdot w \cdot D_{\rm n}}{F}$$
(10)

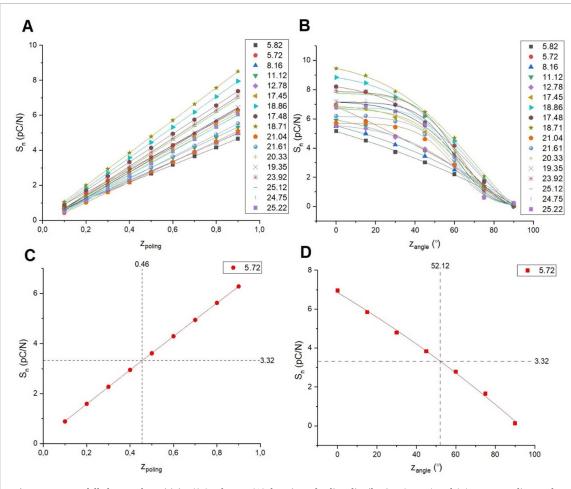


Figure 3. FE-modelled normal sensitivity (S_n) values as (A) function of poling distribution (z_{poling}) and (B) average poling angle (z_{angle}). An example of fitted line for $t_{(PVDF-TrFE)} = 5.72 \ \mu m$ sample with (C) z_{poling} and (D) z_{angle} solved using the experimentally determined S_n value (3.32 pC N⁻¹).

where *F* is the applied compressive force. It is important to note that the relation $S_n \propto P_{r,ratio} \cdot w$ is valid for all force probe geometries (not just the rectangular probe assumed above).

The following stepwise approach was used to relate the poling orientation distribution to the sample geometry and poling condition:

- (a) FE-models for each sample were solved for S_n while sweeping the
 - 1. z_{poling} from 0.1 to 0.9
 - 2. z_{angle} from 0 to 90°
- (b) Regression lines were fitted to the modelled S_n data and solved for the z_{poling} and z_{angle} values which produce the measured S_n values.
- (c) The $P_{r.ratio}$, $t_{P(VDF-TrFE)}$ and *w* were used to create regression model for the z_{poling} and z_{angle} .

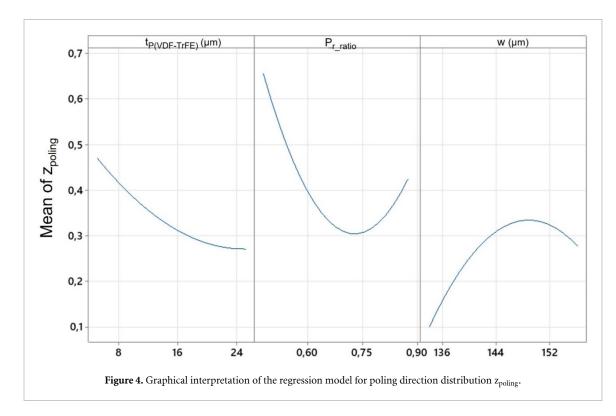
The results of steps 1 and 2 are plotted in figures 3(A) and (B). For all thicknesses, the sensitivity increases as the active area with the poling direction perpendicular to the electrode plane increases (i.e. increase in z_{poling} or decrease in z_{angle}). This can be

qualitatively explained by considering the direction of dominating forces and the magnitude of the activated piezoelectric coefficients in the different poling direction areas of the material: the dominating forces in the S_n measurement are perpendicular to the electrode plane and this leads to activation of d_{33} -coefficient $(-34.9 \text{ pC N}^{-1})$ in the perpendicularly poled material, and activation of lower value *d*-coefficients (e.g. d_{31} -coefficient 10.4 pC N⁻¹) in the parallel poled material. Thus, increasing the portion of perpendicularly poled material should lead to higher sensitivity. The z_{poling} and z_{angle} values producing the experimentally determined S_n value can be then solved from the regression equation as shown in figures 3(C) and (D). The solved z_{poling} and z_{angle} values are summarized in table 1.

The sample geometry and poling condition can be then related to the solved poling orientation by creating a regression model based on the analysis of variance (ANOVA) method. The predictors included in the ANOVA were the $P_{r.ratio}$, $t_{P(VDF-TrFE)}$ and w. Table S3 shows the ANOVA results for the z_{poling} after removing the insignificant predictors using backwards elimination with *P*-value = 0.05 as a criterion;

$t_{P(VDF-TrFE)}$ (μ m)	$S_n (pC N^{-1})$	Z_{poling}	Z_{angle} (°)	$t_{ m P(VDF-TrFE)} \ (\mu { m m})$	$S_n (pC N^{-1})$	Z_{poling}	Z_{angle} (°)
5.82	3.32	0.63	39.68	21.00	1.54	0.29	68.01
5.72	3.32	0.46	52.12	21.60	2.02	0.34	65.98
8.16	3.52	0.63	43.82	20.30	2	0.31	68.48
11.10	2.94	0.49	57.52	19.30	2.2	0.31	69.32
12.80	3.68	0.66	48.82	23.90	2.64	0.34	66.88
17.50	2.64	0.38	65.56	25.10	2.58	0.35	66.32
18.90	2.76	0.31	70.01	24.80	1.44	0.22	71.59
17.50	2.56	0.3	70.15	25.20	2.1	0.33	65.87
18.70	3.1	0.32	69.34				

Table 1. Solved z_{poling} and z_{angle} values based on FE-modelling data.



ANOVA results for z_{angle} are shown in table S4. The resulting regression equations are:

$$z_{\text{poling}} = -17.71 - 0.1912 t_{P(\text{VDF}-\text{TrFE})} - 8.232 P_{\text{r.ratio}} + 0.3027 \text{ w} + 0.000501 t_{P(\text{VDF}-\text{TrFE})} \cdot t_{P(\text{VDF}-\text{TrFE})} + 5.657 P_{\text{r.ratio}} \cdot P_{\text{r.ratio}} - 0.001075 \text{ w} \cdot \text{w} + 0.001145 t_{P(\text{VDF}-\text{TrFE})} \cdot \text{w}$$
(11)

and

$$z_{\text{angle}} = 653 - 10.833 t_{P(VDF-TrFE)} - 439.6P_{\text{r.ratio}} + 11.16w + 0.08754 t_{P(VDF-TrFE)} \cdot t_{P(VDF-TrFE)} + 330.3P_{\text{r.ratio}} \cdot P_{\text{r.ratio}} - 0.0399w \cdot w + 0.04992 t_{P(VDF-TrFE)} \cdot w$$
(12)

where $t_{P(VDF-TrFE)}$ and w are expressed in μ m. Both models fit the data well as is indicated by the high coefficient of determination (R^2) value and low standard deviation of residual (σ): for z_{poling} $R^2 = 98.69\%$ and $\sigma = 0.0201$, and for z_{angle} $R^2 = 99.52\%$ and $\sigma = 0.9265$.

Based on the F-value indicated in tables S3 and S4, the thickness has the strongest effect followed by quadratic term on the P_{r.ratio}, P_{r.ratio}, and w. Graphical interpretation of these results is shown in figure 4 for z_{poling} : increasing the thickness of the P(VDF-TrFE) tends to decrease the amount of poling perpendicular to the electrode plane; P_{r.ratio} has a similar effect with minimum $z_{
m poling} \approx$ 0.75, after which the perpendicular poling starts to again increase; the electrode width has the opposite trend with maximum z_{poling} around 148 μ m. Figure 5 shows that the larger electrode widths decrease the effect of thickness on the z_{poling} . A similar non-linear relationship between the piezoelectric layer thickness, the electrode width and the poling orientation has been previously observed by e.g. Toprak and Tigli [9].

The regression equations for z_{poling} (equation (11)) and z_{angle} (equation (12)) can be then used as an

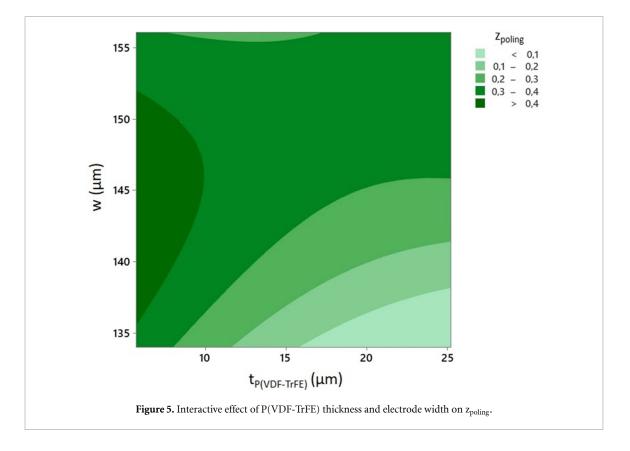


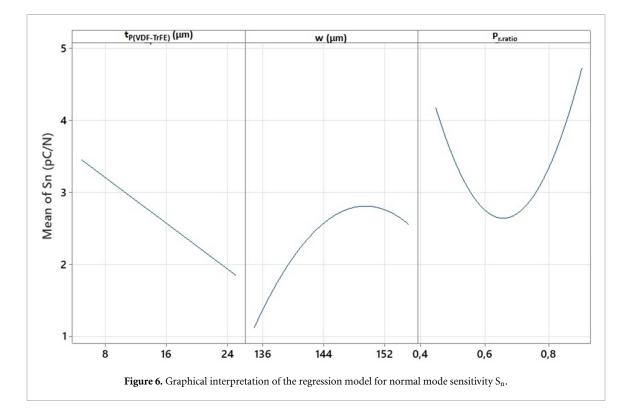
Table 2. Comparison of FE-modelled Sn for zpoling (Sn.FEM1) and zangle (Sn.FEM2) to the experimentally determined Sn values (Sn.experiment).

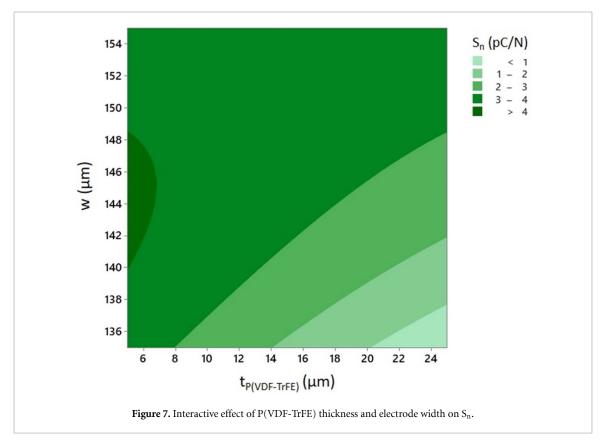
$t_{\mathrm{P(VDF-TrFE)}} (\mu \mathrm{m})$	$S_{n.experiment}$ $(pC N^{-1})$	$S_{n,FEM1} (pC N^{-1})$	$S_{n,\text{FEM2}} (\text{pC}\text{N}^{-1})$	Residual FEM1	Residual FEM2
5.82	3.32	3.42	3.31	-0.10	0.01
5.72	3.32	3.48	3.43	-0.16	-0.11
8.16	3.52	3.55	3.51	-0.03	0.01
11.10	2.94	2.85	3.07	0.09	-0.13
12.80	3.68	3.78	3.64	-0.10	0.04
17.50	2.64	2.86	3.05	-0.22	-0.41
18.90	2.76	2.85	2.88	-0.09	-0.12
17.50	2.56	2.57	2.6	-0.01	-0.04
18.70	3.1	3.28	3.48	-0.18	-0.38
21.00	1.54	1.71	1.76	-0.17	-0.22
21.60	2.02	2.11	2.13	-0.09	-0.11
20.30	2	2.2	2.16	-0.20	-0.16
19.30	2.2	2.31	2.28	-0.11	-0.08
23.90	2.64	2.71	2.91	-0.07	-0.27
25.10	2.58	2.75	3.08	-0.17	-0.50
24.80	1.44	1.75	1.57	-0.31	-0.13
25.20	2.1	1.97	2	0.13	0.10

input in the FE-model to check how well the FEmodelled S_n values correspond to the experimentally determined S_n values. The results are shown in table 2. The standard deviation of the residuals are 0.10 pC N⁻¹ and 0.17 pC N⁻¹, and the R^2 values 94.70% and 88.56% for z_{poling} and z_{angle} based FEmodels, respectively. The z_{poling} based FE-model is therefore the preferable approach for optimization of the geometry and poling condition of the IDE based piezoelectric sensor.

2.4. Optimizing the geometry and poling condition for maximum S_n

Now that the correspondence between the z_{poling} based FEM and experiments has been verified, the FEM can be used to optimize the geometry of the device to reach the maximum S_n value. A design of experiments (DoE) approach was adopted to this end with $P_{r.ratio}$, $t_{P(\text{VDF-TrFE})}$ and w as input and FE-modelled S_n as output; a full factorial central composite design with 20 different parameter combinations





was chosen as this allows the estimation of possible quadratic effects. These are expected due to the previously observed quadratic dependence of z_{poling} on $P_{\text{r.ratio}}$, $t_{\text{P(VDF-TrFE)}}$ and w. The DoE runs and resulting FEM output are shown in tables S5 and S6 shows the ANOVA results after backwards elimination of insignificant predictors using *P*-value = 0.05 as criterion.

The regression model generated based on the ANOVA results is:

$$S_{n} = -139.7 - 1.296t_{P(VDF-TrFE)} + 2.243w$$

- 45.89P_{r.ratio} - 0.00792w · w
+ 34.90P_{r.ratio} · P_{r.ratio}
+ 0.00839t_{P(VDF-TrFE)} · w (13)

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where $t_{P(VDF-TrFE)}$ and *w* are in units μ m and S_n is in units pC N⁻¹. The model fits the data well as is indicated by the high R^2 value of 96.85% and low σ value of 0.1863.

The F-values shown in the table S6 indicate that the quadratic term of $P_{r,ratio}$ has the strongest effect followed by $t_{P(VDF-TrFE)}$ and w. A graphical interpretation of the results is shown in figure 6. The normal mode sensitivity decreases linearly as the thickness of P(VDF-TrFE) is increased, and the $P_{r,ratio}$ and w have minimum and maximum values occurring approximately in the middle of the design space. The parabolic shape originates from the non-linear dependence of poling direction distribution on $P_{r.ratio}$ and w. Omitting the effect of poling direction distribution, increasing P_{r.ratio} would be expected to increase the S_n linearly because as the $P_{r,ratio}$ is increased, the piezoelectrically active width (see equation (10)) increases linearly. The same applies for the electrode width. However, in both cases the non-linear effect induced by the poling direction distribution complicates the shape of the observed effects. The interactive effect of $t_{P(VDF-TrFE)}$ and w (see figure 7) shows that the effect of $t_{P(VDF-TrFE)}$ on S_n decreases as electrode width is increased.

It is interesting to note that the normal mode sensitivity can be increased by reducing the P(VDF-TrFE) thickness. However, we also observed a significant drop in the yield of the poling step due to electric arcing between consecutive IDEs once the P(VDF-TrFE) thickness was reduced below $\sim 5 \mu$ m. This practical limitation was taken into account when determining the boundary conditions for the following parameter optimization.

Finally, the equation (13) can be used to find the optimum sample geometry and poling condition which results in maximum S_n value. The ten best solutions are ranked according to the composite desirability in table S7; the optimum parameter combination occurs at minimum $t_{P(VDF-TrFE)}$ (5 μ m), intermediate w (~144 μ m) and maximum $P_{r,ratio}$ (0.9).

3. Conclusion

A combination of experimental results, statistical modelling and FE-modelling was used to model the non-homogenous poling field of an ultra-thin IDE based piezoelectric sensor. The non-homogenous poling magnitude was estimated based on remanent polarization measurements and two FE-modelling approaches for the non-homogenous poling orientation were compared. The FE-model with the best approach had good correspondence with the experimental results ($R^2 = 94.70\%$ and $\sigma = 0.10$ pC N⁻¹) and it was used to optimize the device geometry and poling condition for maximum normal mode sensitivity.

4. Experimental methods

4.1. Fabrication of the P(VDF-TrFE) sensor

The IDE based and MIM based reference samples were fabricated as described in our previous publications [1] and [2], respectively. See figure S1 for representative microscope images of the IDEs, piezoelectric layer and a final sample.

4.2. Sensor dimensions

The thickness of the P(VDF-TrFE) layer was measured using a stylus profilometer (Dektak XT, Bruker). Each sample was scanned from two locations and the average of these two measurements was used as the thickness. The IDE finger width was measured with an optical microscope (BX60M, Olympus) from three locations and the average of these measurements was calculated.

4.3. Ferroelectric, piezoelectric and electric characterization

The PE loops were measured using the TF 2000 Analyzer (AIXACCT) coupled to a high voltage amplifier (610C, TREK). For IDE based devices, the applied electric field (*E*) was calculated as the ratio of the applied voltage (*V*) and the gap (*g*) between the consecutive electrodes i.e. E = V/G; for MIM based device it was calculated by as ratio of voltage and the thickness of the P(VDF-TrFE) layer (*t*) i.e. E = V/t. The remanent polarization (P_r) values were extracted from the saturated PE-loops.

The normal mode sensitivity (S_n) was measured using PiezoMeter PM300 (Piezotest Ltd) with flat circular probe with a radius of 5 mm while applying 0.25 N of dynamic force with 110 Hz frequency; the sample was clamped between the probes using 10 N of static force.

The capacitance values were measured at 1 kHz frequency using a semiconductor analyzer (B1500A, Keysight).

4.4. Modelling

COMSOL Multiphysics (v.5.6.) with piezoelectric module was used to generate the FE-models. Origin (v. 2019b) was used to fit the regression lines to the FE-modelled data. Minitab Statistical Software (v. 21) was used to perform ANOVA for z_{poling} and z_{angle} results; generate and analyze the DoE; and find the optimum parameters for maximum S_{n} .

Data availability statement

The data generated and/or analyzed during the current study are not publicly available for legal/ethical reasons but are available from the corresponding author on reasonable request.

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Author contributions

M M L: generated the FE and statistical models, analyzed the results, and was the primary author of the manuscript. K L M: fabricated/characterized the samples, contributed to the writing and review of the manuscript. M M contributed the manuscript review.

Conflict of interest

The authors declare no competing interests.

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